

# Vishay General Semiconductor

### **Dual Common Cathode Ultrafast Rectifier**



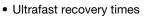
#### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 5.0 A				
$V_{RRM}$	100 V to 200 V				
I <sub>FSM</sub>	55 A				
t <sub>rr</sub>	25 ns				
V <sub>F</sub>	0.895 V				
T <sub>J</sub> max.	150 °C				
Package	TO-220AB				
Circuit configuration	Common cathode				

#### **FEATURES**

- Power pack
- Glass passivated pellet chip junction



- · Soft recovery characteristics
- · Low switching losses, high efficiency
- · High forward surge capability
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency rectifier of switching power supplies, freewheeling diodes, DC/DC converters and polarity protection application.

#### **MECHANICAL DATA**

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

<b>MAXIMUM RATINGS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	UG10BCT	UG10CCT	UG10DCT	UNIT	
PANAMETER	STIMBUL	BYQ28E-100	BYQ28E-150	BYQ28E-200		
Maximum repetitive peak reverse voltage	$V_{RRM}$	100	150	200	V	
Working peak reverse voltage	$V_{RWM}$	100	150	200	V	
Maximum DC blocking voltage	$V_{DC}$	100	150	200	V	
Maximum average forward rectified current at T <sub>C</sub> = 100 °C total device		10			Α	
per diode	I <sub>F(AV)</sub>	5.0				
Peak forward surge current 8.3 ms single half sine-wave	I <sub>FSM</sub>	M 55			Α	
Non-repetitive peak reverse current per diode at $t_p = 100 \mu s$	I <sub>RSM</sub>	0.2			Α	
Electrostatic discharge capacitor voltage, human body model: C = 250 pF, R = 1.5 k $\Omega$	V <sub>C</sub>	8			kV	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub> -40 to +150			°C		



# BYQ28E-xxx, UG10xCT

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT		
Maximum instantaneous forward voltage per diode	I <sub>F</sub> = 10 A	- T <sub>.1</sub> = 25 °C		1.25			
	I <sub>F</sub> = 5 A	V <sub>F</sub> <sup>(1)</sup>	1.10	V			
		T <sub>J</sub> = 150 °C	1	0.895			
Maximum reverse current per diode at working peak reverse voltage		T <sub>J</sub> = 25 °C	- I <sub>R</sub>	10	μΑ		
		T <sub>J</sub> = 100 °C		200			
Maximum reverse recovery time per diode	$I_F = 1.0 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$		t <sub>rr</sub>	25	ns		
Maximum reverse recovery time per diode	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1.0 A, I <sub>rr</sub> = 0.25 A		t <sub>rr</sub>	20	ns		
Maximum stored charge per diode	$I_F = 2 \text{ A}$ , $dI/dt = 20 \text{ A/}\mu\text{s}$ , $V_R = 30 \text{ V}$ , $I_{rr} = 0.1 I_{RM}$		Q <sub>rr</sub>	9	nC		

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse test: 300  $\mu s$  pulse width, 1  $\,\%$  duty cycle

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)				
PARAMETER	CVMPOL	UG10	UNIT	
	SYMBOL	BYQ28E		
Typical thermal resistance per diode, junction to ambient	$R_{\theta JA}$	50	°C/W	
Typical thermal resistance per diode, junction to case	$R_{\theta JC}$	4.5	C/VV	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	BYQ28E-200-E3/45	1.80	45	50/tube	Tube	

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### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

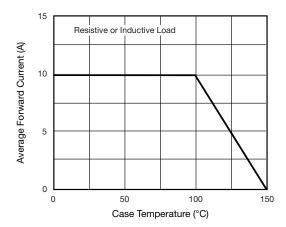


Fig. 1 - Forward Current Derating Curve

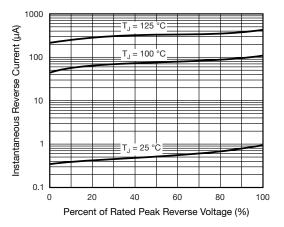


Fig. 4 - Typical Reverse Characteristics Per Diode

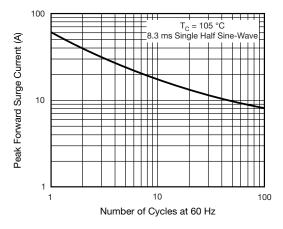


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

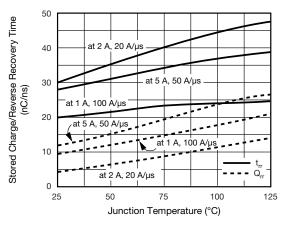


Fig. 5 - Reverse Switching Characteristics Per Diode

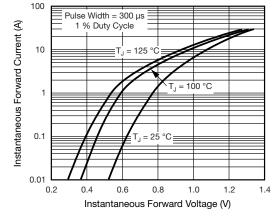


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

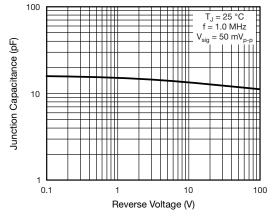
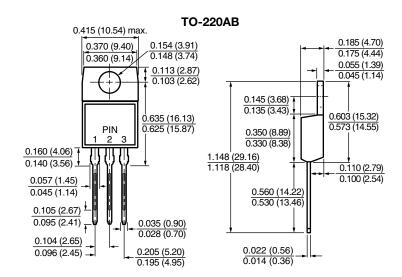


Fig. 6 - Typical Junction Capacitance Per Diode



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### PACKAGE OUTLINE DIMENSION in inches (millimeters)





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